
	<h2 style="color: red;">FQB7P20TM</h2>
	<p>Hersteller-Teilenummer: FQB7P20TM</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 200V 7.3A D2PAK</p> <hr/> <p>Datenblätter:  FQB7P20TM.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 21380 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB7P20TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 200V 7.3A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	21380 pcs Stock
Hersteller Standard Vorlaufzeit	13 Weeks
detaillierte Beschreibung	P-Channel 200V 7.3A (Tc) 3.13W (Ta), 90W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 90W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.3A (Tc)
Rds On (Max) @ Id, Vgs	690 mOhm @ 3.65A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	25nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	770pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FQB7P20TM-ND



















































FQB7P20TM ist neu im Original. Suche FQB7P20TM Datenblätter, PDF, Inventar bei Y-IC.com Online. Bestellen Sie FQB7P20TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB7P20TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB85N06TM_AM002 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 85A D2PAK</p>	 <p>FQB7P06 FSC FQB7P06 FSC</p>	 <p>FQB7P20TM_F085 Fairchild/ON Semiconductor MOSFET P-CH 200V 7.3A D2PAK</p>	 <p>FQB7P20TM Fairchild/ON Semiconductor MOSFET P-CH 200V 7.3A D2PAK</p>
 <p>FQB7P06TM Fairchild/ON Semiconductor MOSFET P-CH 60V 7A D2PAK</p>	 <p>FQB7P20 FSC FQB7P20 FSC</p>	 <p>FQB85N06TM FAIRCHILD FQB85N06TM FAIRCHILD</p>	 <p>FQB7P06TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 7A D2PAK</p>

heiße Teile

Mehr

 FQB6N50TM	 FQB6N60C	 FQB6N60CTM	 FQB6N60CTM	 FQB6N60TM
 FQB6N60TM	 FQB6N70TM	 FQB6N70TM	 FQB6N90TM	 FQB6N90TM_AM002
 FQB6N90TM_AM002	 FQB7042FB	 FQB7045FB	 FQB70N03	 FQB70N06
 FQB70N08	 FQB70N10TM	 FQB7N10L	 FQB7N20L	 FQB7N60TM
 FQB7N60TM	 FQB7N65C	 FQB7N65CTM	 FQB7N65CTM	 FQB7P20TM
 FQB85N06	 FQB85N06TM	 FQB8N25TM	 FQB8N25TM	 FQB8N60C
 FQB8N60CFTM	 FQB8N60CFTM	 FQB8N60CTM	 FQB8N60CTM	 FQB8N60TM
 FQB8N90CTM	 FQB8N90CTM	 FQB8P10TM	 FQB8P10TM	 FQB8P10TM-NL
 FQB9N08L	 FQB9N08LTM	 FQB9N08LTM	 FQB9N25C	 FQB9N25CTM
 FQB9N25CTM	 FQB9N25TM	 FQB9N25TM	 FQB9N50C	 FQB9N50CFTM

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